Vishay Semiconductors

Hyperfast Rectifier, 16 A FRED Pt®





LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS					
I _{F(AV)}	16 A				
V _R	200 V				
V _F at I _F	0.75 V				
t _{rr}	32 ns				
T _J max.	175 °C				
Package	SMPD (TO-263AC)				
Circuit configuration	Single				

FEATURES

- Hyperfast recovery time, reduced Q_{rr}, and soft recovery
- 175 °C maximum operating junction temperature
- Specified for output and snubber operation
- Low forward voltage drop
- · Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers specifically designed with optimized performance of forward voltage drop and hyperfast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in the output rectification stage of SMPS, telecom, DC/DC converters as well as freewheeling diode in low voltage inverters and chopper motor drives.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element.

MECHANICAL DATA

Case: SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating Halogen-free, RoHS-compliant

Terminals: matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Peak repetitive reverse voltage	V _{RRM}		200	V
Average rectified forward current	I _{F(AV)}	T _{solder pad} = 153 °C	16	٨
Non-repetitive peak surge current	I _{FSM}	$T_J = 25 \ ^{\circ}C$, 6 ms square pulse	250	A

ELECTRICAL SPECIFICATIONS (T _J = 25 $^{\circ}$ C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	200	-	-		
Forward voltage V _F	V	I _F = 16 A	-	0.91	1.0	V	
	۷F	I _F = 16 A, T _J = 150 °C	-	0.75	0.84		
Reverse leakage current I _R		$V_{R} = V_{R}$ rated	-	-	15		
		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	150 °C, $V_R = V_R$ rated - 20		500	μA	
Junction capacitance	CT	V _R = 200 V	-	60	-	pF	

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ROHS COMPLIANT HALOGEN





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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS MIN. TYP.			MAX.	UNITS		
		I _F = 1 A, dI _F /dt =	= 50 A/µs, V _R = 30 V	-	32	-			
Poweree receivery time	+	I _F = 0.5 A, I _R = ⁻	I _F = 0.5 A, I _R = 1 A, I _{rr} = 0.25 A		-	32			
Reverse recovery time	t _{rr}	T _J = 25 °C		-	26	-	ns		
		T _J = 125 °C	$I_F = 16 \text{ A},$	-	40	-			
Deels receiver a current		T _J = 25 °C		-	2.8	-	^		
Peak recovery current	I _{RRM}	T _J = 125 °C	$dI_{F}/dt = 200 \text{ A}/\mu \text{s},$ $V_{B} = 160 \text{ V}$	-	6	-	A		
Reverse recovery charge	Q _{rr}	T _J = 25 °C		-	37	-	nC		
		T _J = 125 °C		-	125	-			

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	+175	°C		
Thermal resistance, junction to mount	R _{thJM}		-	1.1	1.4	°C/W		
Approximate weight			0.55			g		
Approximate weight				0.02		oz.		
Marking device		Case style SMPD (TO-263AC)		16EI	DH02			

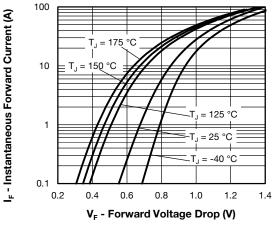


Fig. 1 - Typical Forward Voltage Drop Characteristics

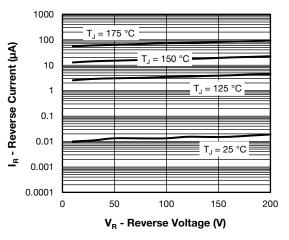


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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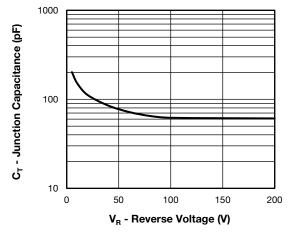


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

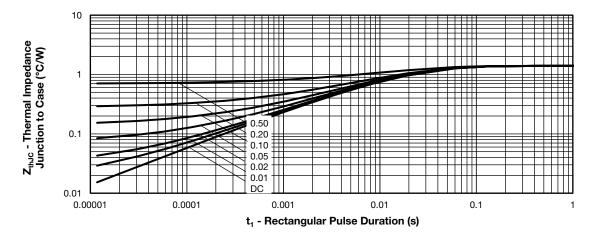
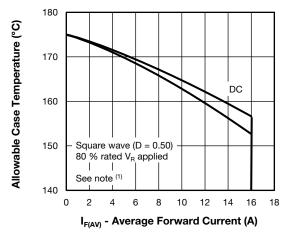
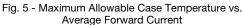


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

Average Power Loss (W)

25





Note

 $^{(1)} \mbox{ Formula used: } T_C = T_J - (Pd + Pd_{REV}) \ x \ R_{thJC}; \\ Pd = \mbox{ forward power loss = } I_{F(AV)} \ x \ V_{FM} \ at \ (I_{F(AV)}/D) \ (see \ fig. \ 5); \\ Pd_{REV} = \mbox{ inverse power loss = } V_{R1} \ x \ I_R \ (1 - D); \ I_R \ at \ V_{R1} = \ rated \ V_R$

20 RMS limit 15 D = 0.01 D = 0.05 10 D = 0.1 D = 0.2 D = 0.5 5 DC 0 15 20 25 0 5 10 I_{F(AV)} - Average Forward Current (A)



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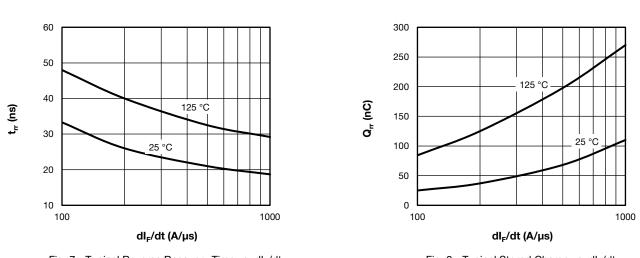


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

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ISHAY



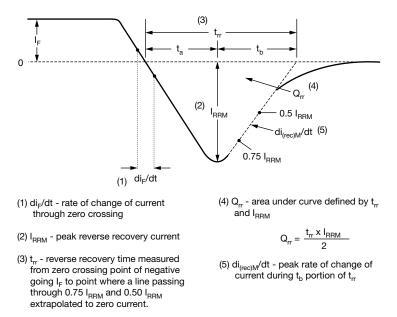


Fig. 9 - Reverse Recovery Waveform and Definitions

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ORDERING INFORMATION TABLE

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Device code	vs-	16	Е	D	н	02	-МЗ
	1	2	3	4	5	6	7
	1	- Visl	nay Sem	nicondu	ctors pr	oduct	
	2	- Cur	rent rati	ng (16 A	A)		
	3 ·	- Circ	cuit conf	figuratio	n:		
		E =	single d	lie			
	4	- D =	SMPD	package	e		
	5	- Pro	cess typ	be,			
		H =	hyperfa	ast recov	/ery		
	6	- Volt	tage coo	de (02 =	200 V)		
	7	M3	3 = halog	gen-free	e, RoHS	-compli	iant, and

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER REEL	QUANTITY PER REEL MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-16EDH02-M3/I	2000	2000	13" diameter plastic tape and reel					

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95604				
Part marking information	www.vishay.com/doc?95566				
Packaging information	www.vishay.com/doc?88869				
SPICE model	www.vishay.com/doc?96785				

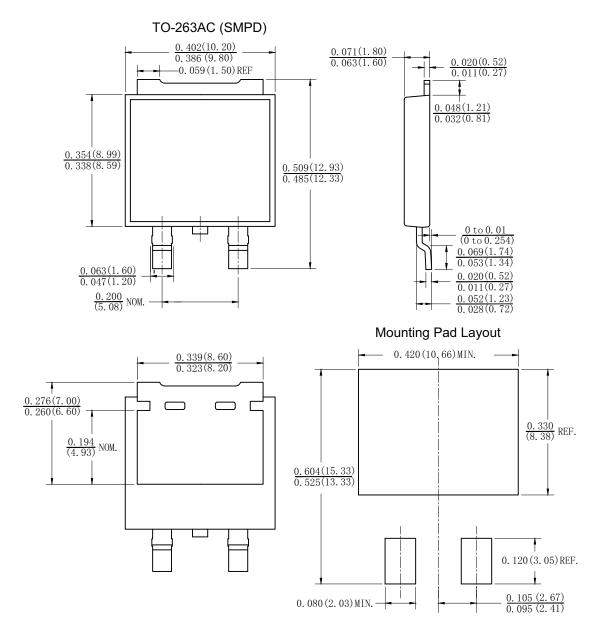
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TO-263AC (SMPD)

DIMENSIONS in inches (millimeters)







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